

- RC-IGBTs optimized for industrial applications
  Upward compatibility with conventional IGBT and FWD chipsets
- Higher current density contributes to equipment miniaturization
  Rated current increased from 1200V/600A → 1000A
- High heat dissipation, high tracking resistance package Significant improvement in the heat spreading with high performance ceramic substrate



Application examples: Motor drives, UPSs, solar power generation, and wind power generation



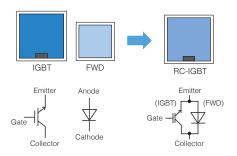


### 1. RC-IGBTs optimized for industrial applications

RC-IGBTs, which are widely used in automotive application, are now available for industrial application with optimized design and performance. Following advantages are expected with upward compatibility with the conventional IGBT and FWD chipsets.

- Reverse conduction ability of RC-IGBTs can replace and remove FWDs. This contribute to significant increase in chip mountable area for larger, higher current rating chips. The larger chip area also reduce the junction to case thermal resistance significantly.
- Compatible with the same design methods and control circuits as conventional IGBTs. No custom gate drivers are needed.

#### I-V curve characteristics comparison 200 T<sub>vi</sub>= 25°C 150 Collector Current : Ic [A] 100 50 Conventional IGBT chip 0 -50 -100 RC-IGBT chip -150 -200 L -3.0 -2.0 -10 0.0 10 20

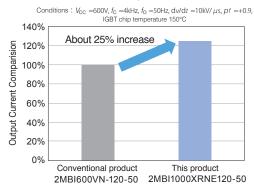


RC-IGBT chip schematic and equivalent circuit

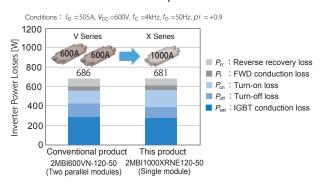
# 2. Higher current density contributes to equipment miniaturization

By applying RC-IGBT technologies, in comparison with our conventional V series product in the same Dual XT package, the maximum rated current has been increased from 1200V/600A to 1000A. Thus, the output current during steady-state continuous operation can be expanded by about 25%. This increased output make it possible, for example, to replace two 600A modules in parallel with a single 1000A module in a 350kW inverter. This contributes to equipment miniaturization and also reduce the number of gate drivers.

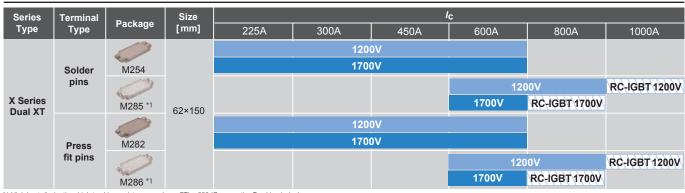
## Output current comparison during steady-state continuous operation



### 350 kW inverter loss comparison



#### Product series 1200V/1700V



### \*1 High heat dissipation, high tracking resistance package CTI = 600 (Comparative Tracking Index)

### Safety Precautions

\*Before using this product, read the "Instruction Manual" and "Specifications" carefully, and consult with the retailer from which you purchased this product as necessary to use this product correctly. \*The product must be handled by a technician with the appropriate skills.

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